



SANYO Semiconductors

DATA SHEET

LB1882V — Monolithic Digital IC

Three-phase Brushless Motor Driver

Overview

LB1882V is a 3-phase brushless motor driver IC that is optimal for driving the spindle motors in portable AV equipment such as DAT, CD and MD products.

Features

- Small external capacitors due to the current linear drive scheme
- Low power enabled by motor voltage control
- Operates on supply voltage down to 1.8V
- Built-in torque ripple correction circuit
- Built-in saturation prevention circuit
- Built-in AGC circuit
- Built-in thermal shutdown circuit
- Built-in current limiter
- Built-in FG amplifier

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	$V_{CC1\text{ max}}$		8	V
	$V_{CC2\text{ max}}$		12	V
	V_S		V_{CC1}	V
Maximum output current	$I_O\text{ max}$		1.0	A
Allowable power dissipation	$P_d\text{ max}$		0.5	W
Operating temperature	T_{opr}		-20 to +75	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

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Allowable Operating Ranges at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage	V_{CC1}		1.8 to 6.0	V
	V_{CC2}		3 to 10	V
	V_S		to V_{CC1}	V

Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC1} = 2.5\text{V}$, $V_{CC2} = 4.5\text{V}$, $V_S = 1\text{V}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Current drain	I_{CC1}			5	8	mA
	I_{CC2}				2	mA
	I_S	$I_S - I_L$			1	mA
Output quiescent current	I_{CC1OQ}	$V_{STBY}=0\text{V}$			10	μA
	I_{CC2OQ}	$V_{STBY}=0\text{V}$			10	μA
	I_{SOQ}	$V_{STBY}=0\text{V}$			10	μA
Output saturation voltage upper side	$V_{OU}(\text{sat})1$	$V_{RF}=40\text{mV}$, $R_L=100\Omega$ (Y)	25		65	mV
	$V_{OU}(\text{sat})2$	$V_{RF}=100\text{mV}$, $R_L=100\Omega$ (Y)	25		65	mV
Output saturation voltage lower side	$V_{OD}(\text{sat})1$	$V_{RF}=40\text{mV}$, $R_L=100\Omega$ (Y)	200		280	mV
	$V_{OD}(\text{sat})2$	$V_{RF}=100\text{mV}$, $R_L=100\Omega$ (Y)	285		365	mV
Hall amplifier input offset voltage	$V_{H\text{offset}}$	Design target*	-5		+5	mV
Hall amplifier common-mode input voltage range	$V_{H\text{COM}}$		1.2		2.5	V
Standby pin high-level voltage	V_{STBYH}		2.0			V
Standby pin low-level voltage	V_{STBYL}				0.4	V
Standby pin input current	I_{LSTBY}	$V_{STBY}=4.5\text{V}$			120	μA
Standby pin leakage current	I_{LSTBY}	$V_{STBY}=0\text{V}$	-30			μA
FRC pin high-level voltage	V_{FRCH}		1.6			V
FRC pin low-level voltage	V_{FRCL}				0.4	V
FRC pin input current	I_{IFRC}	$V_{FRC}=4.5\text{V}$			100	μA
FRC pin leakage current	I_{LFRC}	$V_{FRC}=0\text{V}$	-30			μA
Thermal shutdown circuit operating temperature	T_{TSD}	Design target*	150	180	210	$^\circ\text{C}$
Thermal shutdown hysteresis	ΔT_{TSD}	Design target*		15		$^\circ\text{C}$
FG Amplifier						
Common-mode input voltage range	V_{ICR}		1.2		3.3	V
Input offset voltage	V_{IO}	Design target*	-5		+5	mV
Output saturation voltage	V_{SINK}	$R_L=10\text{k}\Omega$			0.2	V
Output current (sink)	I_{SINK}				2	mA

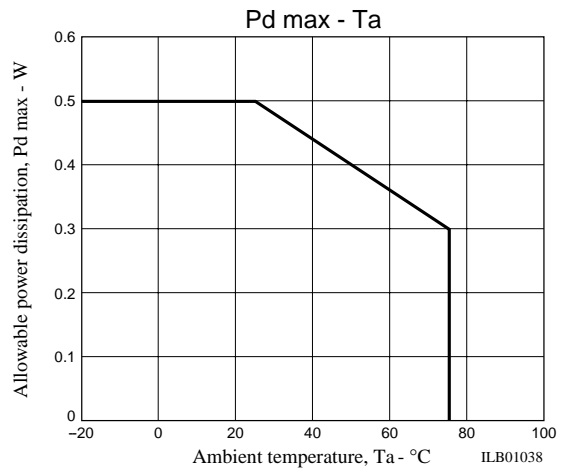
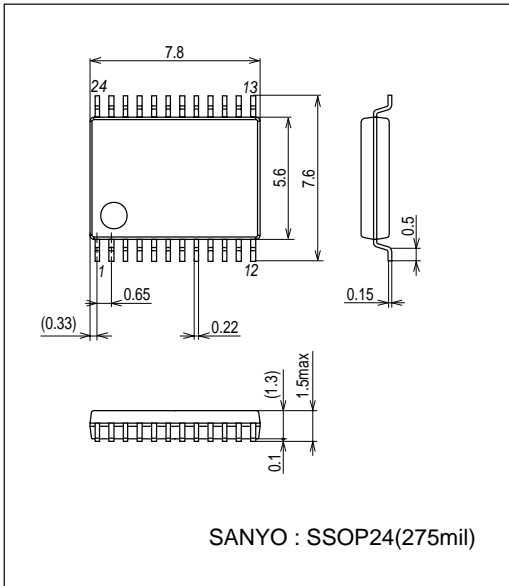
*: Design target value and no measurement was made.

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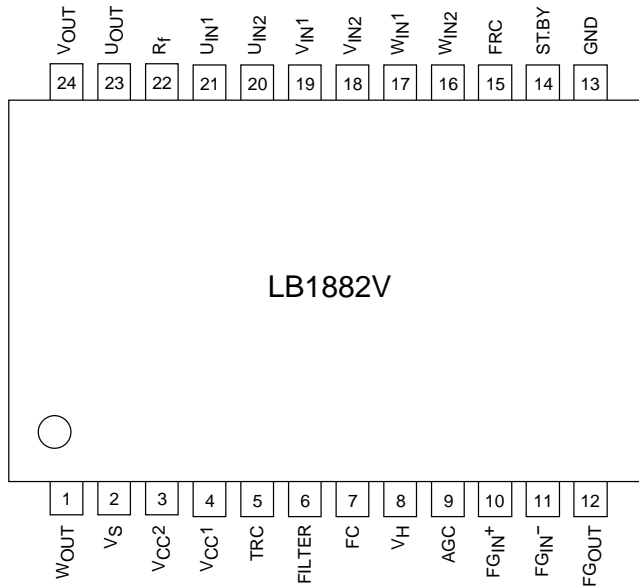
Package Dimensions

unit : mm (typ)

3175C



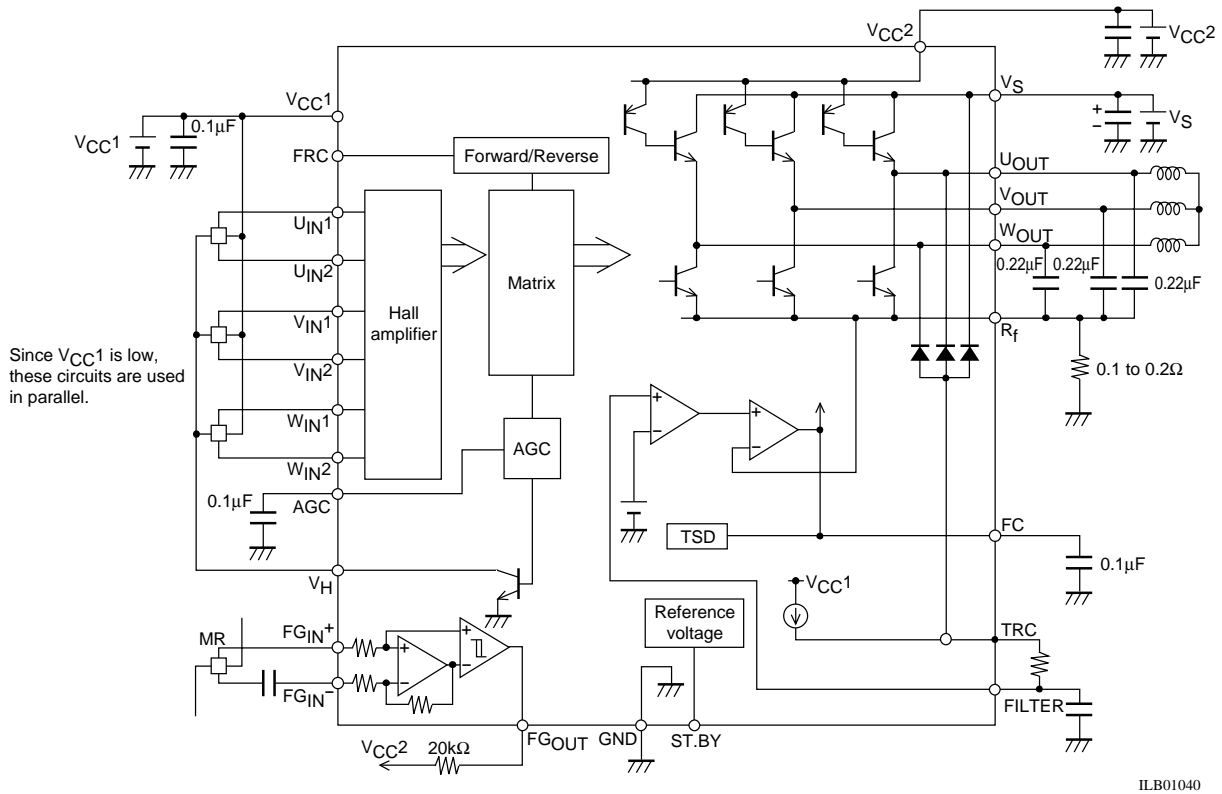
Pin Assignment



Top view

ILB01039

Block Diagram and Sample Application Circuit



Truth Table

	Source → Sink	Input			Forward/reverse control
		U	V	W	
1	W → V	H	H	L	L
	V → W				H
2	W → U	H	L	L	L
	U → W				H
3	V → W	L	L	H	L
	W → V				H
4	U → V	L	H	L	L
	V → U				H
5	V → U	H	L	H	L
	U → V				H
6	U → W	L	H	H	L
	W → U				H

Inputs: "H" means that the input 1 potential for the corresponding phase is at least 0.2V higher than the input 2 potential.

"L" means that the input 1 potential for the corresponding phase is at least 0.2V lower than the input 2 potential.

Forward/reverse control: "H": 1.6V to V_{CC2}
 "L": 0V to 0.4 V

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Pin Functions

Pin No.	Symbol	Pin Voltage	Pin Function	Equivalent Circuit
2	V_S	$\leq V_{CC1}$	Power supply that provides the motor voltage and determines the output amplitude. This voltage must be lower than V_{CC1} .	
3	V_{CC2}	$\geq V_{CC1}$ 3V to 10V	Power supply that provides the voltage for the source side pre-drive PNP transistor and the FG amplifier.	
4	V_{CC1}	1.8V to 6V	Power supply that provides all voltages other than the motor voltage, the source side pre-drive voltage, and the FG amplifier voltage.	
5	TRC		Coil output waveform lower side envelope waveform detection.	<p style="text-align: right;">ILB01041</p>
6	FILTER		The coil output saturation prevention function operates using an RC filter (a resistor between this pin and the TRC pin and a capacitor between this pin and ground) connected at this pin. Motor speed (r.p.m.) control can then be achieved by adjusting the voltage on pin V_S . The torque ripple correction amount can be adjusted by adjusting the external RC constant.	<p style="text-align: right;">ILB01042</p>
7	FC		Frequency characteristics correction. The capacitor connected between this pin and ground stops closed-loop oscillation in the current control system.	<p style="text-align: right;">ILB01043</p>
8	VH		The Hall elements are connected between this pin and V_{CC1} . The AGC circuit adjusts the Hall bias current so that the amplitude of the Hall element remains fixed. Since the Hall amplifier common-mode voltage range is reduced when a low voltage is used for V_{CC1} , the Hall elements should be connected in parallel.	<p style="text-align: right;">ILB01044</p>

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Pin No.	Symbol	Pin Voltage	Pin Function	Equivalent Circuit
9	AGC		A capacitor is inserted between this pin and ground. The AGC circuit controls the Hall bias current so that the coil output slope remains fixed.	<p style="text-align: right;">ILB01045</p>
10 11	FG _{IN+} FG _{IN-}	1.2V min 3.3V max	FG amplifier input.	<p style="text-align: right;">ILB01046</p>
12	FG _{OUT}	V _{CC2} max	FG amplifier output.	<p style="text-align: right;">ILB01047</p>
13	GND		Ground for all circuits other than the output circuits.	
14	ST, BY	V _{CC2} max	All circuits stop when this pin falls below 0.4V or is open. In this state, the circuit current will be 10μA or lower. Set this pin to 2V or higher to operate the LB1882V in the motor drive state.	<p style="text-align: right;">ILB01048</p>
15	FRC	V _{CC2} max	Motor forward/reverse switching. Low level: Forward (0 to 0.4V) High level: Reverse (1.6V to V _{CC2})	<p style="text-align: right;">ILB01049</p>

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Pin No.	Symbol	Pin Voltage	Pin Function	Equivalent Circuit
16 17 18 19 20 21	W_{IN2} W_{IN1} V_{IN2} V_{IN1} U_{IN2} U_{IN1}	1.2V min 2.5V max ($T_a=25\text{ }^\circ\text{C}$ $V_{CC1}=2.5\text{V}$)	W-phase Hall element input. The logic high level is the state where $W_{IN1} > W_{IN2}$. V-phase Hall device input. The logic high level is the state where $V_{IN1} > V_{IN2}$. U-phase Hall device input. The logic high level is the state where $U_{IN1} > U_{IN1}$.	
22 23 24 1	RF U_{OUT} V_{OUT} W_{OUT}		Output transistor ground. Detecting the voltage on this pin is used to implement fixed current drive and the current limiter function. U-phase output V-phase output W-phase output	

Functional Description

The LB1882V implements a current linear drive method, and controls the motor speed with the motor power supply voltage by always preventing coil output saturation and holding the output saturation voltage fixed.

(1) Control system (see page 8)

- The TRC pin outputs a signal consisting of the coil output voltage lower-side envelope plus the diode rising voltage.
- The TRC waveform, after the high-frequency components are reduced by a low-pass filter consisting of an RC circuit connected to the FILTER pin, is input to the FILTER pin. The cutoff frequency is $1/2\pi \cdot RC$.
- The FILTER pin voltage is input to the control amplifier plus side. The control amplifier minus side is connected to the reference voltage and the control amplifier operates to hold the FILTER pin at the same potential as this reference voltage. As long as this reference voltage exceeds the output transistor saturation voltage, the coil output will operate in the unsaturated state.
- The output current (the RF current) operates as a fixed current drive since the RF voltage is held at a fixed level by the second stage of the control amplifier.

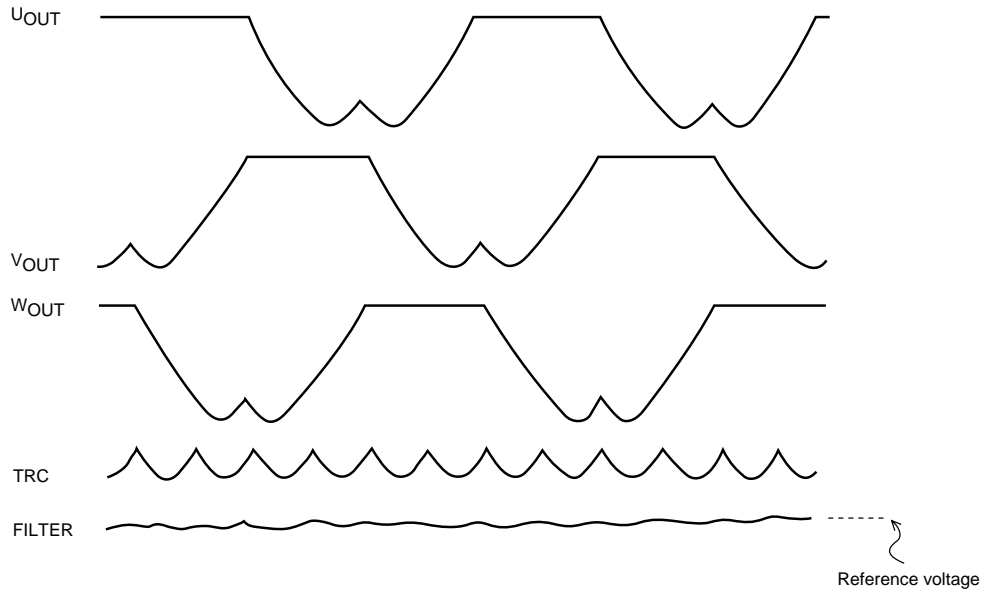
Note: The low-frequency components that are not removed by the TRC pin RC filter function as motor torque ripple correction signals.

(2) Drive system (See page 8.)

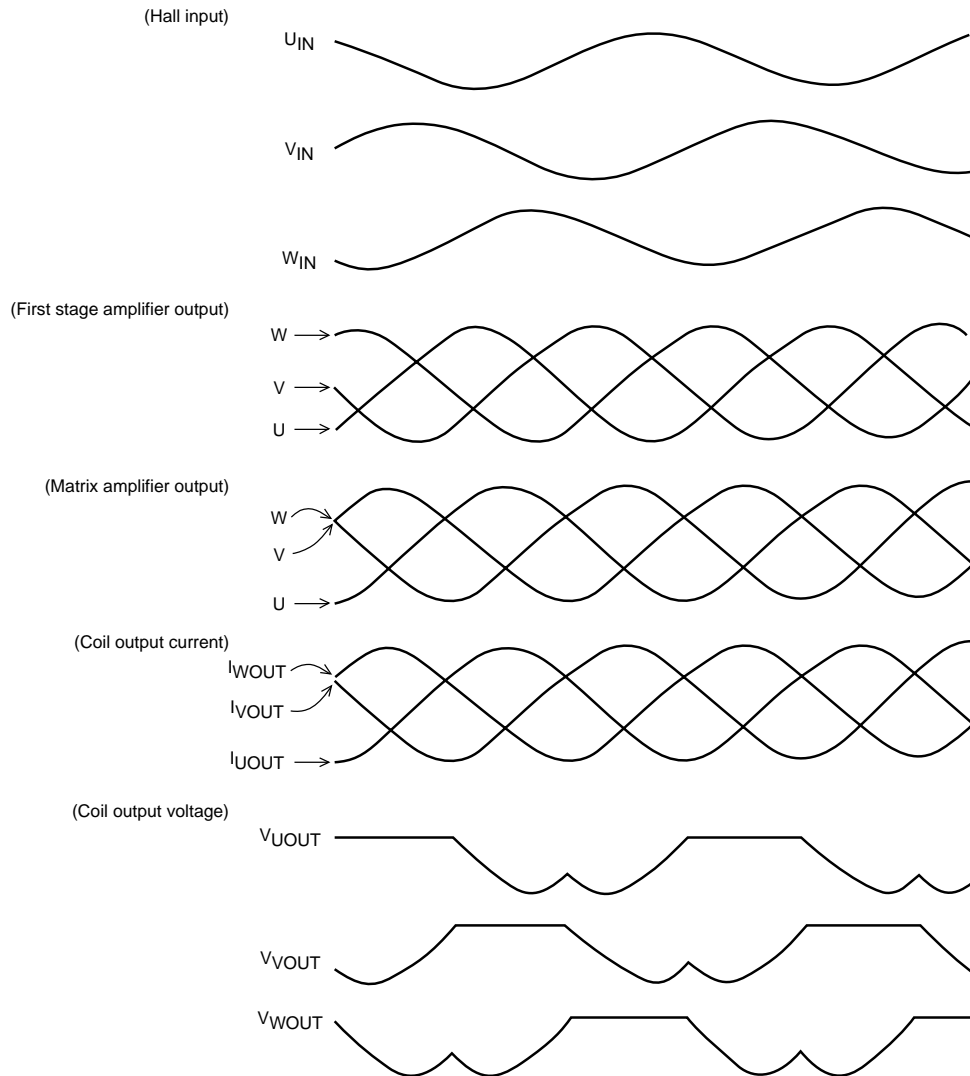
- The Hall element output is wave shaped by the first stage of the Hall amplifier.
- The Hall amplifier output waveform is synthesized by the matrix amplifier, which creates a waveform phase delayed by 30° .
- This waveform is voltage-to-current converted and is then further current amplified and output as the coil current by the power amplifier. Since the upper and lower transistor drive ratios differ here (the upper transistor drive ratio is larger), the upper side voltage waveform is saturated, and the lower-side voltage waveform is unsaturated.

Note: The AGC circuit controls the Hall bias current so that the matrix amplifier output waveform has a fixed amplitude.

Control System Signal Flow



Drive System Signal Flow



ILB01052

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